WNSC2D30650CW



Rev.01 - 16 December 2021

Product data sheet

1. General description

WeEn Semi

Dual Silicon Carbide Schottky diode in a 3-lead TO247 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- Highly stable switching performance
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- High Forward Surge Capability I_{FSM}
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
 - Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	V _{RRM} repetitive peak reverse 650 voltage					V	
I _{O(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 117 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		30		А	
T_j	junction temperature		175		°C		
Symbol	Parameter	Conditions	Min Typ Max		Unit		
Static ch	aracteristics						
V _F	forward voltage	$I_F = 15 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.45	1.7	V
		I_{F} = 15 A; T_{j} = 150 °C; per diode; <u>Fig. 5</u>		-	1.65	1.9	V
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 15 \text{ A}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s}; \text{ V}_R = 400 \text{ V};$ $T_j = 25 \text{ °C}; \text{ per diode}; Fig. 7$		-	24	-	nC

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	К	cathode		
3	A2	anode		<u> </u>
mb	mb	mounting base; connected to cathode		sym125

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WNSC2D30650CW	TO247	WNSC2D30650CWQ	Tube	30	SOT429	25-Mar-2013		

7. Marking

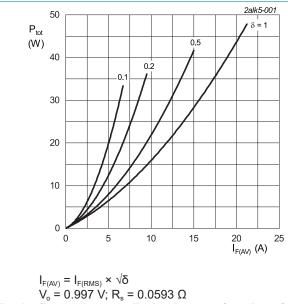
Table 4. Marking codes							
Type number	Marking codes						
WNSC2D30650CW	WNSC2D 30650CW						

8. Limiting values

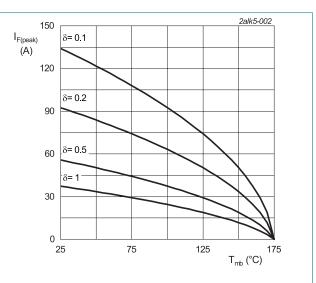
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V _{RRM}	repetitive peak reverse voltage		650	V
V _{RWM}	crest working reverse voltage		650	V
V _R	reverse voltage	DC	650	V
I _{O(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 117$ °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	30	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 123 °C; square-wave pulse; per diode	30	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	85	A
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse; per diode	900	A
l ² t	l ² t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; t_p = 10 ms	36	A ² s
T _{stg}	storage temperature		-55 to 175	°C
Tj	junction temperature		175	°C



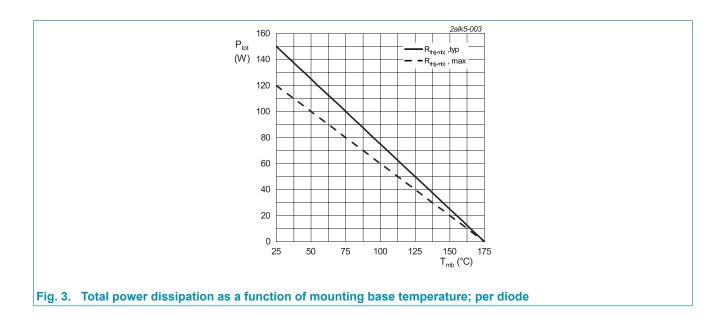
V_o = 0.997 V; R_s = 0.0593 Ω
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode





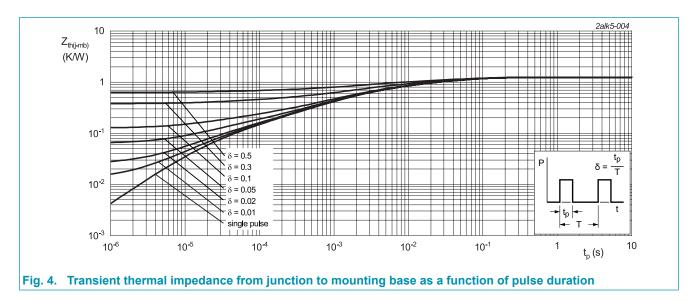
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WNSC2D30650CW Silicon Carbide Diode



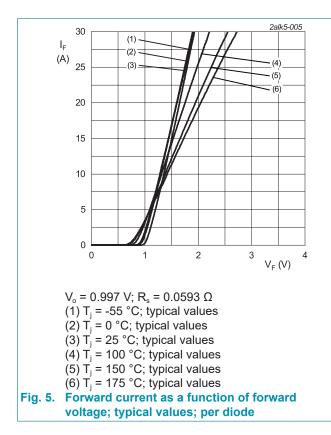
9.	Thermal	characteristics

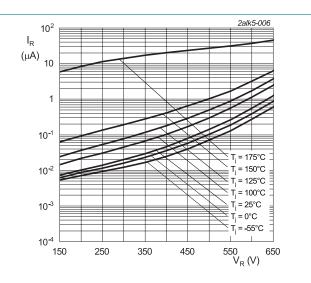
Table 6. Th	ermal characteristics		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	per diode; <u>Fig. 4</u>	-	1	1.25	K/W
		both diodes conducting	-	-	0.7	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W



10. Characteristics

Table 7. Cl	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
$V_{\rm F}$	forward current	$I_{F} = 15 \text{ A}; T_{j} = 25 \text{ °C}; \text{ per diode}; Fig. 5$	-	1.45	1.7	V
		$I_F = 15 \text{ A}; T_j = 150 \text{ °C}; \text{ per diode}; Fig. 5$	-	1.65	1.9	V
		$I_F = 15 \text{ A}; T_j = 175 \text{ °C}; \text{ per diode}; Fig. 5$	-	1.72	2.1	V
I _R	reverse current	$V_{R} = 650 \text{ V}; \text{ T}_{j} = 25 \text{ °C}; \text{ per diode}; \text{Fig. 6}$	-	3	50	μA
		V_{R} = 650 V; T _j = 175 °C; per diode; <u>Fig. 6</u>	-	18	200	μA
Dynamic	characteristics					
Qr	recovered charge	$I_F = 15 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ per diode}; Fig. 7$	-	24	-	nC
C _d	diode capacitance	f = 1 MHz; V_R = 1 V; T_j = 25 °C; per diode	-	500	-	pF
		f = 1 MHz; V_R = 300 V; T_j = 25 °C; per diode	-	58	-	pF
		f = 1 MHz; V_R = 600 V; T_j = 25 °C; per diode	-	52	-	pF
E _{as}	non-repetitive avalanche energy	$I_R = 6.3 \text{ A}; L = 5 \text{ mH}; T_{j(init)} = 25 \text{ °C};$ per diode	99	-	-	mJ

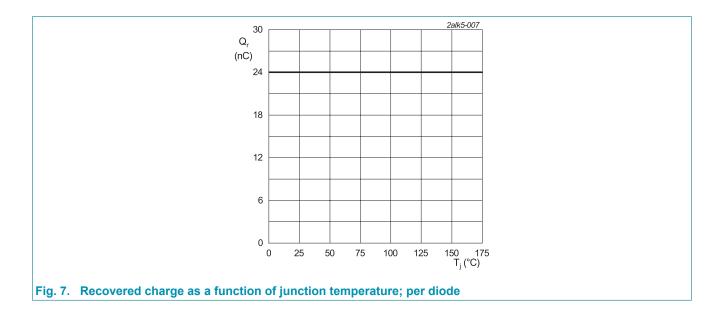






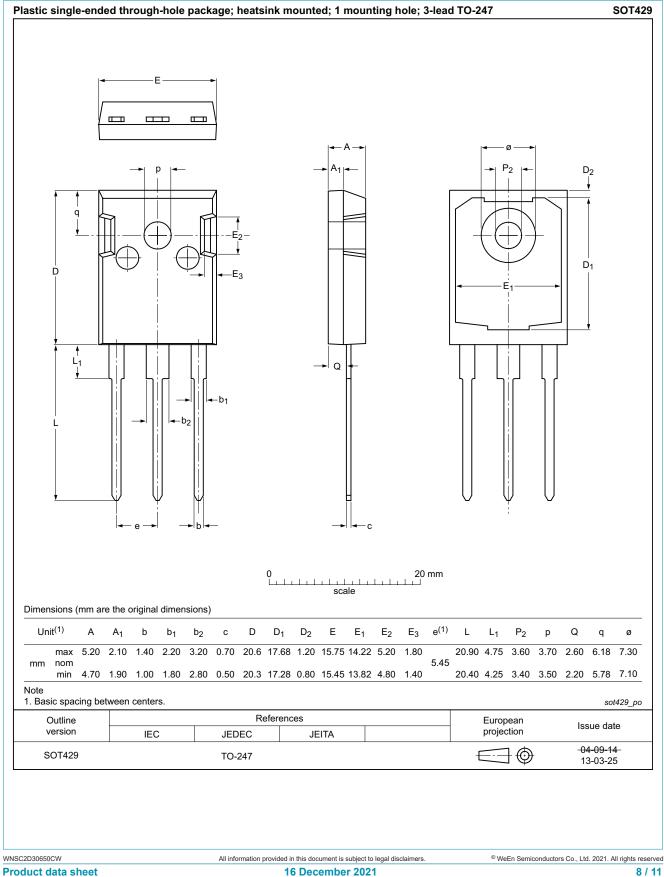
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Silicon Carbide Diode



WNSC2D30650CW Silicon Carbide Diode

11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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